## NSN 5961-01-314-9634

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-314-9634 **Inclosure Material:** Plastic **Overall Length:** 0.790 inches **Terminal Length:** 0.200 inches **Overall Width:** 0.710 inches Lens Transparency: Transparent all light emitting diode **Function For Which Designed:** Visible light emitting **Component Name And Quantity:** 6 light emitting diode **Mounting Method: Terminal Semiconductor Material:** Gallium phosphide all light emitting diode Voltage Rating In Volts Per Characteristic: 3.0 reverse voltage, instantaneous all light emitting diode **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current preset all light emitting diode **Power Rating Per Characteristic:** 450.0 milliwatts small-signal input power, common-collector preset all light emitting diode **Color Tone Produced Per Source:** Red lens all light emitting diode **Luminous Intensity:** 17.0 millicandela all light emitting diode **Maximum Operating Tempurature Per Measurement Point:** 70.0 degrees celsius ambient air **Special Features:** All light emitting diode junction pattern arrangement: pn **Terminal Type And Quantity:** 12 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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